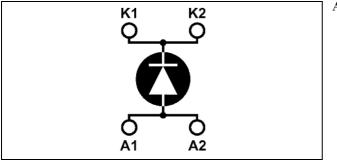


APTDF400U120G

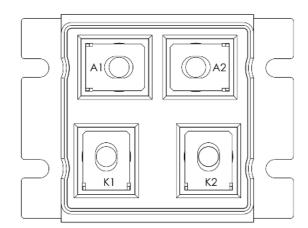
Single diode Power Module





Application

- Anti-Parallel diode
 - Switchmode Power Supply
 - Inverters
 - Snubber diode
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers
- Electric vehicles



Absolute maximum ratings

Features

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current

Benefits

- Low losses
 - Low noise switching
 - Direct mounting to heatsink (isolated package)
 - Low junction to case thermal resistance

• •

RoHS Compliant

| | Symbol | Parameter | | | Max ratings | Unit |
|---|--|--|------------------------|---------------------|-------------|------|
| | V _R | Maximum DC reverse Voltage | | | 1200 | V |
| | V _{RRM} | Maximum Peak Repetitive Revers | 1200 | v | | |
| ſ | т | AV) Maximum Average Forward Current | $D_{\rm retri} = 500/$ | $T_c = 25^{\circ}C$ | 450 | |
| | $\mathbf{I}_{\mathrm{F}(\mathrm{AV})}$ | | Duty cycle = 50% | $T_c = 80^{\circ}C$ | 400 | А |
| | I _{F(RMS)} | RMS Forward Current | | | 750 | 11 |
| | I _{FSM} | Non-Repetitive Forward Surge Current $T_j = 25^{\circ}C$ | | | 5000 | |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified



Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|-----------------|---------------------------------|--|------------------------|-----|-----|------|------|
| | Diode Forward Voltage | $I_F = 500A$ | | | | 2.5 | |
| $V_{\rm F}$ | | $I_{\rm F} = 1000 {\rm A}$ | | | 2.5 | | V |
| | | $I_{\rm F} = 500 {\rm A}$ | $T_{j} = 150^{\circ}C$ | | | 2.0 | |
| т | Maximum Reverse Leakage Current | $T_i = 25^{\circ}C$ | $T_i = 25^{\circ}C$ | | | 2500 | A |
| I _{RM} | | $V_{\rm R} = 1200V$ $T_{\rm j} = 125^{\circ}C$ | | | | 5000 | μA |
| CT | Junction Capacitance | $V_R = 200V$ | | | 600 | | pF |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|--------------------|----------------------------------|---|------------------------|-----|------|-----|---------|
| t _{rr1} | Reverse Recovery Time | $I_F=1A, V_R=30V$ di/dt = 15A/µs | $T_j = 25^{\circ}C$ | | 90 | | |
| t _{rr2} | | $I_F = 500A$ | $T_j = 25^{\circ}C$ | | 110 | | ns |
| t _{rr3} | | $V_{R} = 650V$ di/dt=1000A/µs | $T_{j} = 100^{\circ}C$ | | 175 | |] |
| $t_{\rm fr1}$ | – Forward Recovery Time | | $T_j = 25^{\circ}C$ | | 220 | | ns |
| t _{fr2} | | | $T_{j} = 100^{\circ}C$ | | 220 | | 115 |
| I _{RRM1} | – Reverse Recovery Current | | $T_j = 25^{\circ}C$ | | 70 | | Α μC |
| I _{RRM2} | | | $T_{j} = 100^{\circ}C$ | | 120 | | |
| Q _{rr1} | – Reverse Recovery Charge | $I_{\rm F} = 500 \text{A}$ $V_{\rm R} = 650 \text{V}$ | $T_j = 25^{\circ}C$ | | 10 | | |
| Q _{rr2} | | $di/dt=1000A/\mu s$ | $T_{j} = 100^{\circ}C$ | | 30 | | μυ |
| $V_{\rm fr1}$ | Forward Recovery Voltage | | $T_j = 25^{\circ}C$ | | 26 | | v |
| V _{fr2} | | | $T_{j} = 100^{\circ}C$ | | 26 | | |
| d _{IM/dt} | Rate of Fall of Recovery Current | | $T_j = 25^{\circ}C$ | | 1200 | | A/µs |
| ∽nvi/dt | | | $T_{j} = 100^{\circ}C$ | | 800 | | 40 |

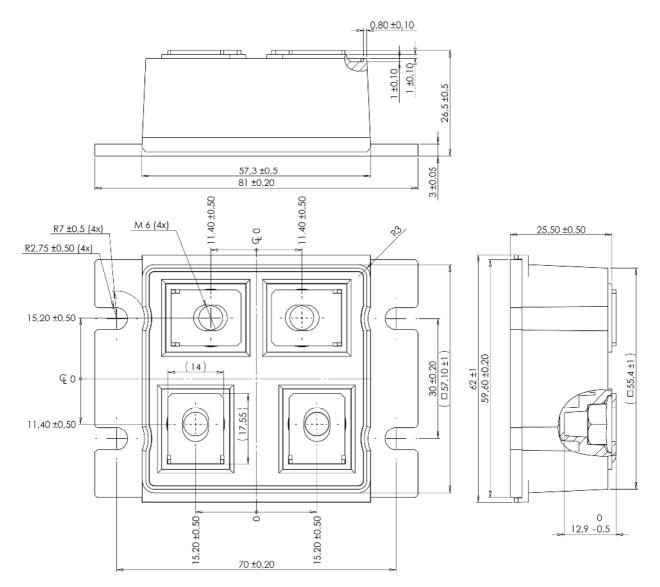
Thermal and package characteristics

| Symbol | Characteristic | | Min | Тур | Max | Unit | |
|-------------------|---|---------------|-----|------|-----|------|--------|
| R _{thJC} | Junction to Case Thermal Resistance | | | | | 0.08 | °C/W |
| V _{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | 4000 | | | V |
| T _J | Operating junction temperature range | | -40 | | 150 | | |
| T _{STG} | Storage Temperature Range | | | -40 | | 125 | °C |
| T _C | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To heatsink | M5 | 2.5 | | 3.5 | N.m |
| Torque | | For terminals | M6 | 3 | | 4 | 19.111 |
| Wt | Package Weight | | | | | 250 | g |

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LP4 Package outline (dimensions in mm)



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